

1A Fast Recovery Bridge Rectifier

Features

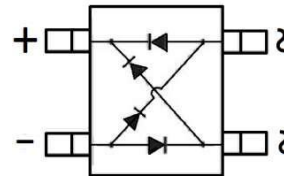
- Glass Passivated Chip Junction
- Reverse Voltage : 50 to 1000V
- Forward Current : 1A
- High Surge Current Capability
- High temperature soldering : 260°C/10s at terminals



ABS

Applications

- High-frequency switching power supply
- PFC circuit



Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbol	RABS05	RABS1	RABS2	RABS4	RABS6	RABS8	RABS10	Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at $T_C=125^\circ\text{C}$	$I_{F(AV)}$	1.0							A
Peak Forward Surge Current 8.3mS single half sine wave superimposed on rated load(JEDEC method)	I_{FSM}	30							A
Maximum Instantaneous Forward Voltage at 1.0A	V_F	1.3							V
Maximum DC Reverse Current at Rated DC Blocking Voltage	$T_A=25^\circ\text{C}$	10							μA
	$T_A=125^\circ\text{C}$	100							
Maximum Reverse Recovery Time $T=25^\circ\text{C}$ (Note 3)	T_{RR}	150			250		500		nS
Typical Junction Capacitance(Note 1)	C_J	15							pF
Typical Thermal Resistance(Note 2)	$R_{\theta JA}$	80							$^\circ\text{C}/\text{W}$
Operating Junction Temperature Range	T_J, T_{STG}	(-55 to +150)							$^\circ\text{C}$

Notes:

1. Measured at 1.0MHz and applied reverse voltage of 4.0 Volts.
2. Reverse Recovery Test Conditions: $I_f=0.5\text{mA}$, $I_r=1.0\text{mA}$, $I_{rr}=0.25\text{A}$

Ratings and Characteristic Curves ($T_A=25^\circ\text{C}$ unless otherwise noted)

Fig. 1 Derating Curve for Output Rectified Current

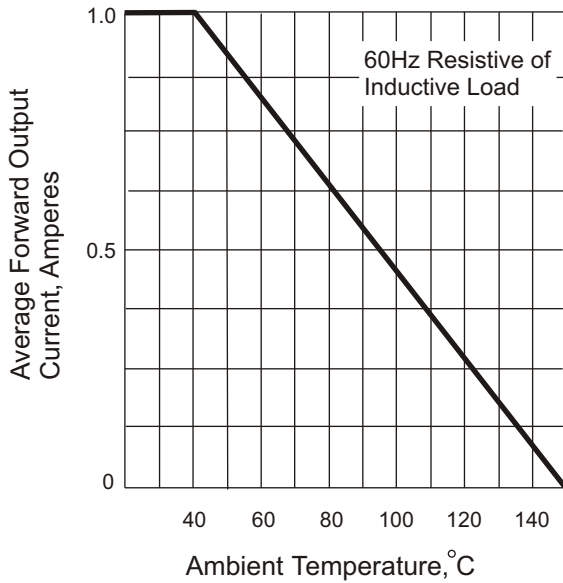


Fig. 2 Maximum Non-repetitive Peak Forward Surge Current

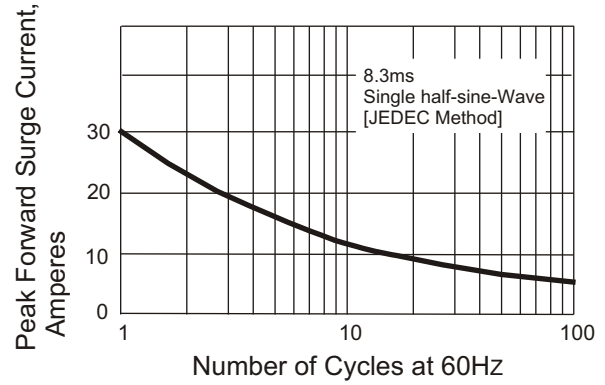


Fig. 3 Typical Instantaneous Forward Characteristics

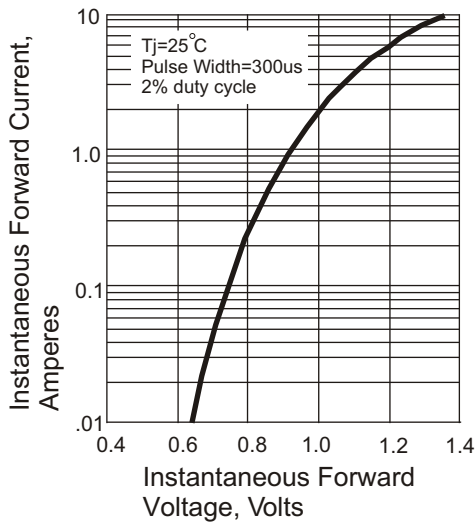


Fig. 4 Typical Reverse Characteristics

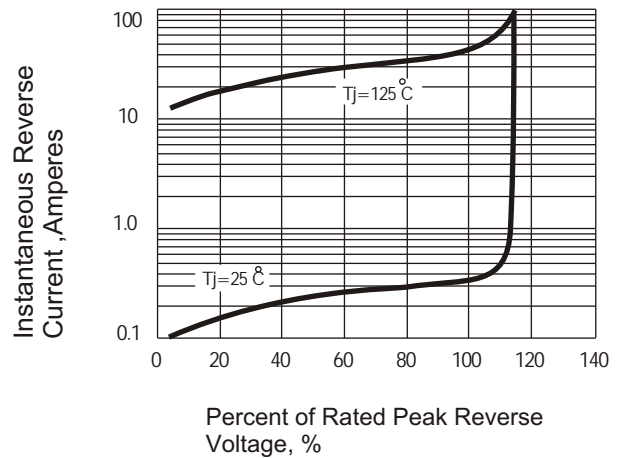
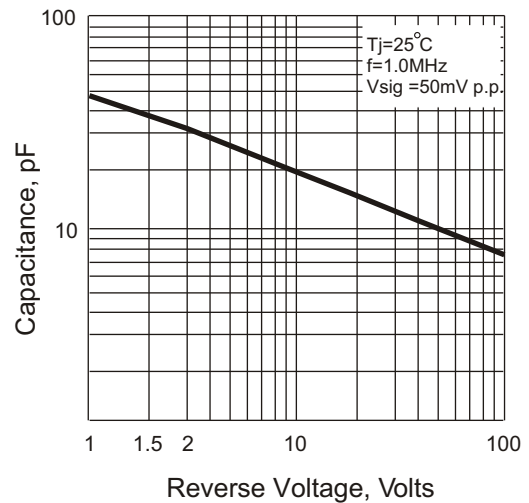
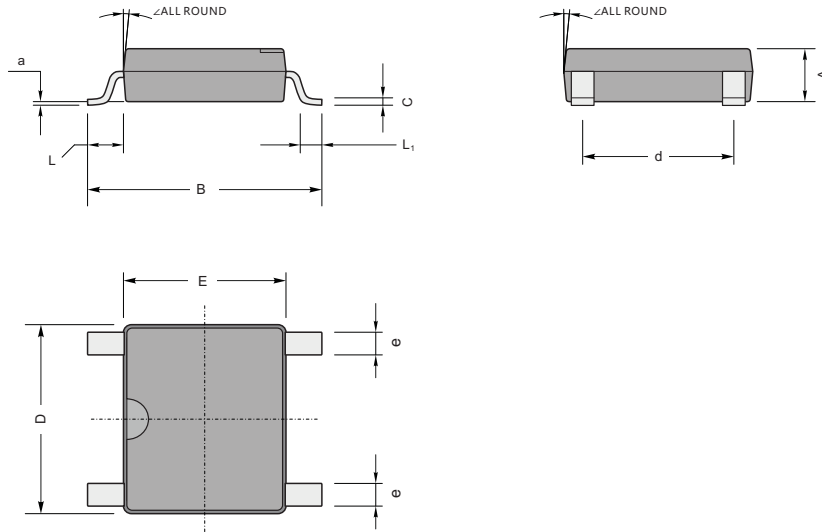


Fig. 5 Typical Junction Capacitance



Package Outlines (Dimensions in mm)

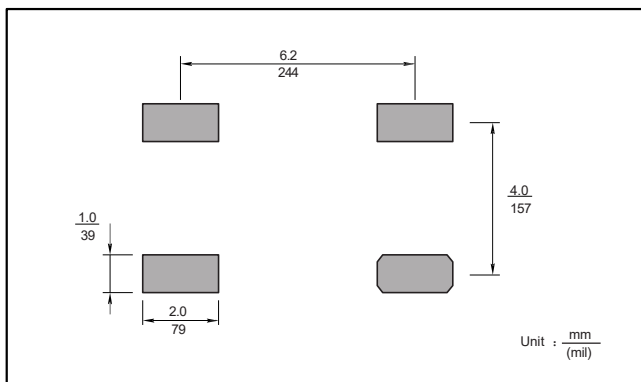
Plastic surface mounted package(ABS)



ABS mechanical data

UNIT		A	C	D	E	B	d	e	L	L ₁	a	∠
mm	max	1.5	0.22	5.3	4.6	6.5	4.2	0.7	0.95	0.6	0.2	5°
	min	1.3	0.15	5.0	4.3	6.1	3.8	0.5				
mil	max	59	8.7	209	181	256	165	28	37	24	8	
	min	51	5.9	197	169	240	150	20				

The recommended mounting pad size



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